Computer simulation studies of HF adsorption on TiO₂ (001) and (110) surfaces

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Abstract. Hydrogen fluoride molecule is a candidate used for etching metal oxide surface due to its strong corrosive qualities. However, the etching phenomenon is not well understood at the atomistic level. Investigation of HF interaction with TiO_2 (001) and (110) surfaces is important for enhancing the etching mechanism. Adsorption geometries and energies of HF on TiO_2 (001) and (110) surfaces have been investigated using density functional theory employing CASTEP code. It was found that HF chemically adsorbed to TiO_2 (001) and (110) surfaces to form Ti-F bond and hydroxyl molecule. The adsorption of HF molecule on TiO_2 (001) and (110) surface with lower adsorption energy than on (110) surface. Besides, all these surfaces were found to have higher adsorption ability with increasing number of HF molecules. Mulliken charge analysis indicates that the dissociation of F atom attract electrons, due to the higher electronegativity of the fluorine atom.

1. Introduction

Titanium and its alloyed components are extensively used materials for a large variety of applications [1]. The adsorption of oxygen during the manufacturing of these metal components remain a big concern that results in the formation alpha case layer [2]. Surface modification is required due to the spontaneous growth of alpha case layer. Recently, wet chemical etching process remains a widely applied technique for surface modification using hydrogen fluoride (HF) as an etchant [3, 4]. HF is a colorless fuming liquid or gas molecule materials mainly used for industrial purpose such as metal surface etching. Metal surface etching by HF is one of the most important material tailoring technique in the manufacturing of metal-based alloyed components [5] therefore, it is very important to understand the interaction of HF with TiO₂ surfaces. Adsorption of HF by suitable solid adsorbents seems to offer an interesting and practical atomic interaction.

Considerable research effort has been expended for HF adsorption on the metal oxide surface [6, 7]. These studies, however, tend to have a focus on the Al_2O_2 [8], SiO_2 [9] surfaces and adsorption of a single prone molecule. Recently, Yang *et al* [10] showed that the adsorption of fluorine (F) ion on the surfaces of anatase-TiO₂ makes (100) surface energetically preferable than (101) surface. Wang *et al* [11] investigated selective etching phenomenon on (001) surface faceted anatase titanium dioxide. Their

results indicated that etching mechanism is energetically permitted and the surface etching can merely occur on the (100) surface under high HF concentrations. In this work density functional theory (DFT) approach is used to study the adsorption behavior of HF on TiO_2 (110) and (001) surfaces at different coverages. The adsorption energy, charge density difference and Mulliken charge are analyzed.

2. Computational methodology

First-principle calculations were performed using CASTEP code as implemented in Material Studio [12] on the basis of density functional theory (DFT). The electron-exchange and correlation were described by the Perdew-Burke-Ernzerhof (PBE) functional of the generalized gradient approximation (GGA) [13]. The GGA-PBE functional is well known to underestimate the band-gap which reduces photo-induced electron transfer during reactions [14]. To correct the strong electronic correlation problem, DFT+U method which was first initiated by Dudarev *et al* [15] was utilized with a U parameter of 5.0 eV for Ti in TiO₂ as proposed by Dompablo *et al* [16]. Brillouin-zone integrations are implemented using the Monkhorst-Pack approach [17] with K-point sampling grids of $4 \times 4 \times 1$ for geometry calculation with cut-off energy of 400 eV. The TiO₂ (001) and (110) surfaces were represented by $p(2 \times 2)$ and $p(3 \times 3)$ supercell with five and seven atomic layers, respectively. In order to eliminate the interaction between two adjacent TiO₂, a vacuum of 30 Å was adopted. The interaction strength of HF molecule with the TiO₂ (001) and (110) surfaces is given by the adsorption energy, calculated using the equation below:

$$E_{ads} = [E_{HF/slab} - (E_{slab} + E_{HF})]$$
(1)

where $E_{HF/slab}$ is the total energy of the surface slab with molecule, E_{slab} is the energy of the surface slab and E_{HF} is the energy of the isolated molecule.

3. Results and discussion

3.1 Surface geometry and HF Adsorption

Pure surface slabs were initially optimized to obtain surface energetic minima and examine chemical properties. Figure 1 (a-b) shows the optimized surface slabs with designated atom coordination, (a) TiO_2 (110) surface consisting of three coordinating oxygen atom (O3c) and both titanium five- and six-coordination atoms (Ti5c and Ti6c), respectively. (b) TiO_2 (001) surface consist of two coordinate oxygen atoms (O2c) and five coordinates titanium (Ti5c). Surface optimization reveal that TiO_2 (110) surface is much more stable with a lower surface energy of (1.98 Jm⁻²) than TiO_2 (001) surface (2.81 Jm⁻²).



Figure 1: TiO_2 model surface slabs: (a) (110) and (b) (001) surface.

Calculated surface energies are well comparable with the results by Idrizz *et al* [18] and Tshwane *et al* [19]. The significant differences on the surface energy of TiO₂ (110) obtained by Tshwane *et al* [19], is due to different surface slabs. Adsorption process involves the interaction of HF molecule with TiO₂ (001) and (110) surfaces and one of the most fundamental characteristics of the process is the adsorption energy. Table 1 present the adsorption energies and the optimized parameters of HF molecule interacting with TiO₂ (110) and (001) surfaces. The negative value of adsorption energies indicates that the adsorption of HF molecule on Ti (001) and (110) surfaces is energetically favourable. TiO₂ (001) surface was found to be the most favourable adsorption surface than TiO₂ (110) surface with adsorption energy of -5.92 eV and -5.43 eV, respectively. The smaller E_{ads} value suggest very large exothermicity of the adsorption process. The relative difference in adsorption energy with a different surface is due to atom surface interaction and bonding.

Surface slab	E _{ads} physisorption	E_{ads} chemisorption	Bond length Å		
		-	Ti-F	Ti-O	О-Н
(001)-Ti5c	-5.92	-2.79	1.927	2.075	0.997
(110)-Ti5c	-5.43	-2.67	1.965	2.059	1.015
(110)-Ti6c	-4.93		1.984	2.086	1.022

Table 1: The optimized structure parameters and adsorption energies of HF on the TiO_2 (110) and (001) surfaces.

Both physisorption and chemisorption were considered to investigate the nature of HF adsorption. The physisorption is the adsorption by bonding, whereas chemisorption is the adsorption without bonding. Comparing the adsorption energies, it was found that HF adsorption is by physisorption than chemisorption process. Figure 2 (a-b) present the optimized geometric structures of HF adsorption on Ti (110) and (001) surfaces. It was observed that HF dissociates completely when adsorbed on the TiO₂ (110) and (001) surfaces, with a hydrogen atom bonded to the oxygen atom forming hydroxyl while fluorine is bonded to five- and six-fold coordinated Ti atoms (Ti-F). The bond length of hydroxyl is about 0.99-1.022 Å and bond length of Ti-F is approximately 1.927-1.984 Å.



Figure 2: Optimized geometric structures of (a) $HF-TiO_2$ (110) and (b) $HF-TiO_2$ (001) surface.

The adsorption energies are shown to be the most thermodynamically favorable configuration. Figure 3 shows the dependence of adsorption energies per HF coverage on TiO_2 (110) and (001) surfaces. Results revealed that the adsorption energy become more stable with increasing HF coverage, this trend has been observed in several systems in the past [20]. However, the adsorption energies on (001) surface were found to be more stable than on (110) surface for all HF coverages. Therefore, attractive interaction between the HF molecules with the surface contribute to this phenomenon.



Figure 3: The adsorption energy of HF on TiO_2 (110) and (001) surfaces at different coverages.

3.2 Charge density difference and Mulliken Charge analysis

The interaction between the adsorbate and adsorbent implies a significant charge transfer. Charge density difference (CDD) between HF molecule with TiO_2 (001) and (110) surfaces were calculated using equation below:

$$\Delta \rho = \rho_{\underline{adsorbate}} - \rho_{slab} - \rho_{adsorbate} \tag{2}$$

Adsorption Energy (eV) 10 6- 8- 2- 9- 5-11

-4





Figure 4: The charge density difference of HF adsorption on TiO_2 (a) (110) and (b) (001) surfaces with iso-surface value of 0.05 eV/Å³.

Table 2 present Mulliken charge analysis for pure and adsorbed TiO_2 (110) and (001) surfaces. The Mulliken charge of Ti atoms in (001) and (110) surface are 1.34 e and 1.00 e, respectively. However, after adsorption Mulliken charge of Ti atoms increased to 1.47 e and 1.11 e for (001) and (110) surfaces, respectively. Comparing Mulliken charge analysis of clean surfaces and after adsorption, it is seen that electrons are transferred between HF molecule and TiO_2 (001) and (110) surfaces via F-Ti bonding. The electron transferred between F-Ti interaction for (001) surface is -0.13 e while for (110) surface is -0.11 e. This is due to the higher electronegativity of F atom than Ti atom.

Table 2: Mulliken charge analysis for Ti and F/Ti atoms.

surfaces	Mulliken Charge Analysis (e)				
	Ti	F/Ti	Δe		
(001)	1.34	-0.49/1.47	-0.13		
(110)	1.00	-0.51/1.11	-0.11		

4. Conclusion

DFT calculations were employed to investigate the adsorption behaviour of HF molecule on TiO₂ (001) and (110) surfaces. It was found that HF molecule dissociates completely to form Ti-F and O-H bond. Adsorption behaviour of HF molecule is energetically favourable on TiO₂ (001) surface than on TiO₂ (110) surface. The adsorption energy value reveals that adsorption of HF molecule on TiO₂ (001) and (110) surfaces is by physisorption than chemisorption process, due to the stronger interaction between the F- ion and Ti atoms. The adsorption energy becomes more stable with increasing HF molecule coverage indicating that HF molecule coverage is thermodynamically stable. The interaction induced charge redistribution, according to charge density difference and Mulliken charge analysis it shows that HF-TiO₂ (001) and (110) surfaces have charge transferred process. Specifically, the electrons on the Ti atoms were transferred to HF molecule. This analysis showed patterns of electron accumulation and

depletion at the Ti-F interaction. Mulliken charge analysis indicated that titanium atom loses electrons whereas fluorine gains an additional electron during the interaction.

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